



| | Value | Unit |
|--|--------------|-------------|
| | 60 | V |
| | 1.5 | V |
| | 91 | A |
| | 2.6 | mΩ |
| | 3.2 | m |



Electrical Characteristics ($T_J = 25^\circ\text{C}$ unless otherwise specified)

| Symbol | Conditions | Min. | Typ. | Max. | Unit |
|----------------------------|------------|------|------|-----------|-----------|
| Off Characteristics | | | | | |
| $V_{(BR)DSS}$ | | 60 | - | - | V |
| I_{DSS} | | - | - | 1.0 | μ |
| I_{GSS} | | - | - | ± 100 | |
| $V_{GS(th)}$ | | 1.1 | 1.5 | 2.5 | V |
| | | - | 2.6 | 3.3 | $m\Omega$ |
| | | - | 3.2 | 4.2 | $m\Omega$ |
| R_g | | - | 2.1 | - | Ω |
| C_{iss} | | 2140 | 3566 | 5349 | pF |



Typical Performance Characteristics

Figure 1: Power De-rating

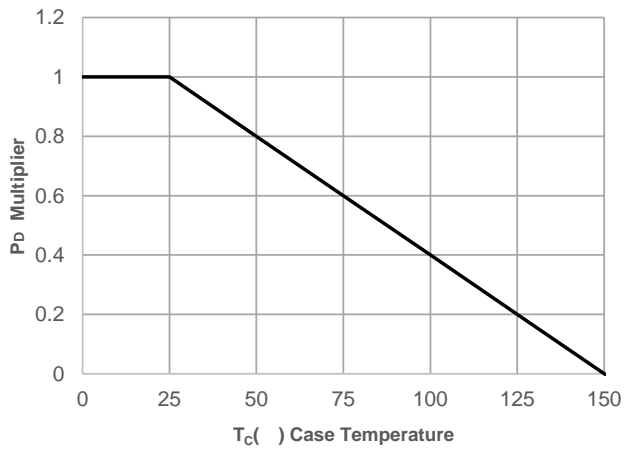
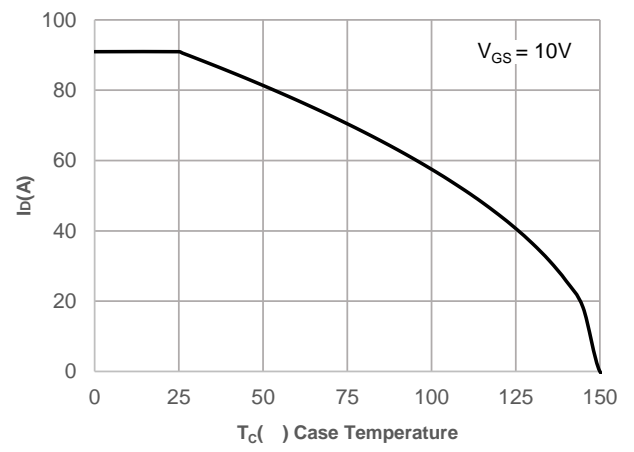
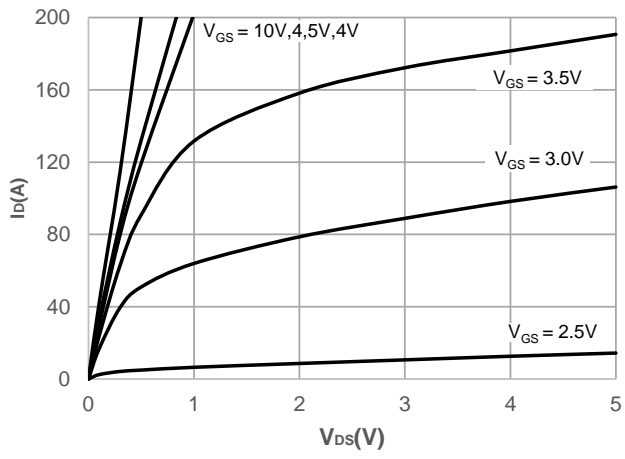


Figure 2: Current De-rating



Typical Performance Characteristics

Figure 5: Output Characteristics



Typical Performance Characteristics

Test Circuit



Figure 1: Gate Charge Test Circuit & Waveform

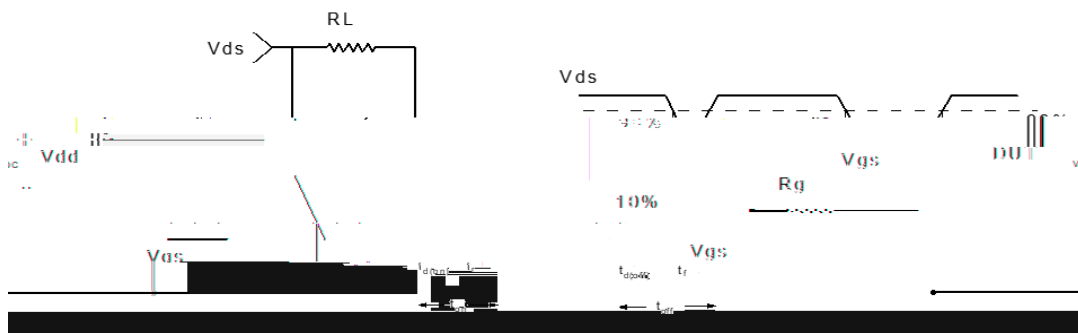


Figure 2: Resistive Switching Test Circuit & Waveform

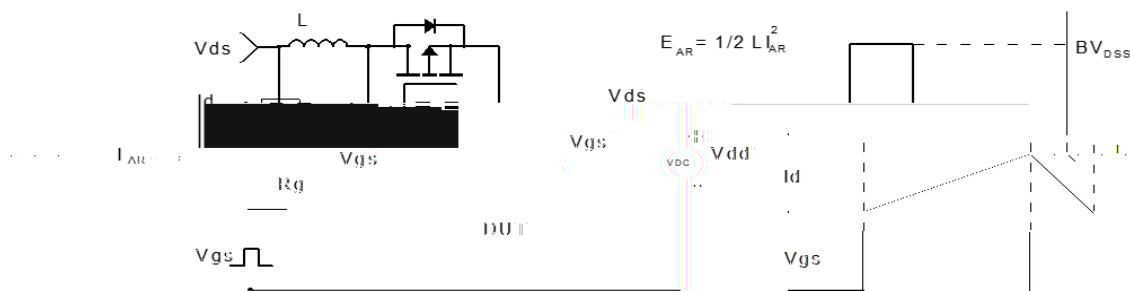


Figure 3: Unclamped Inductive Switching Test Circuit & Waveform

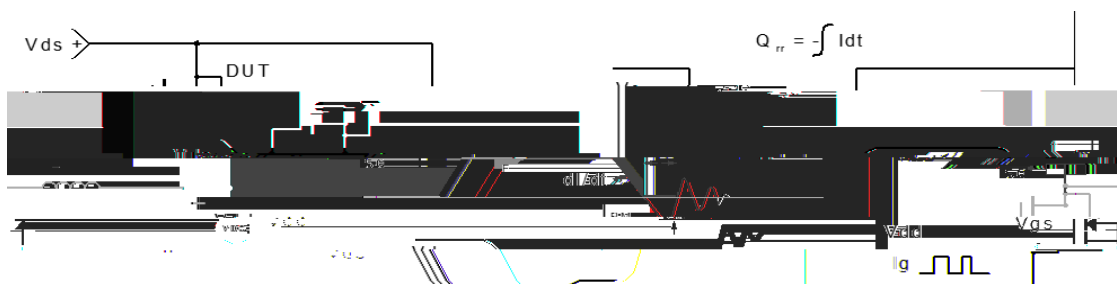


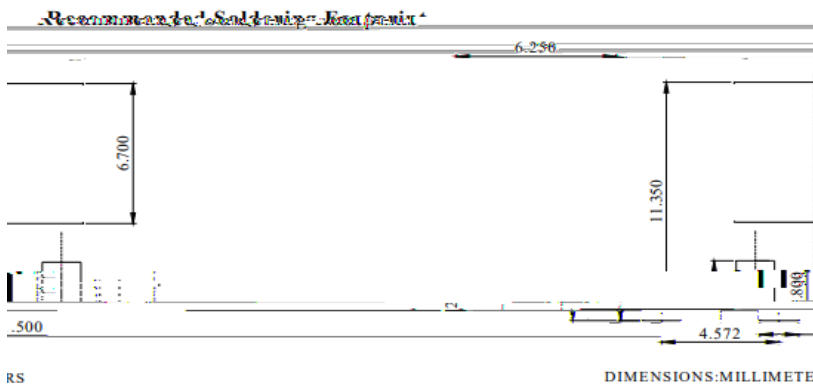
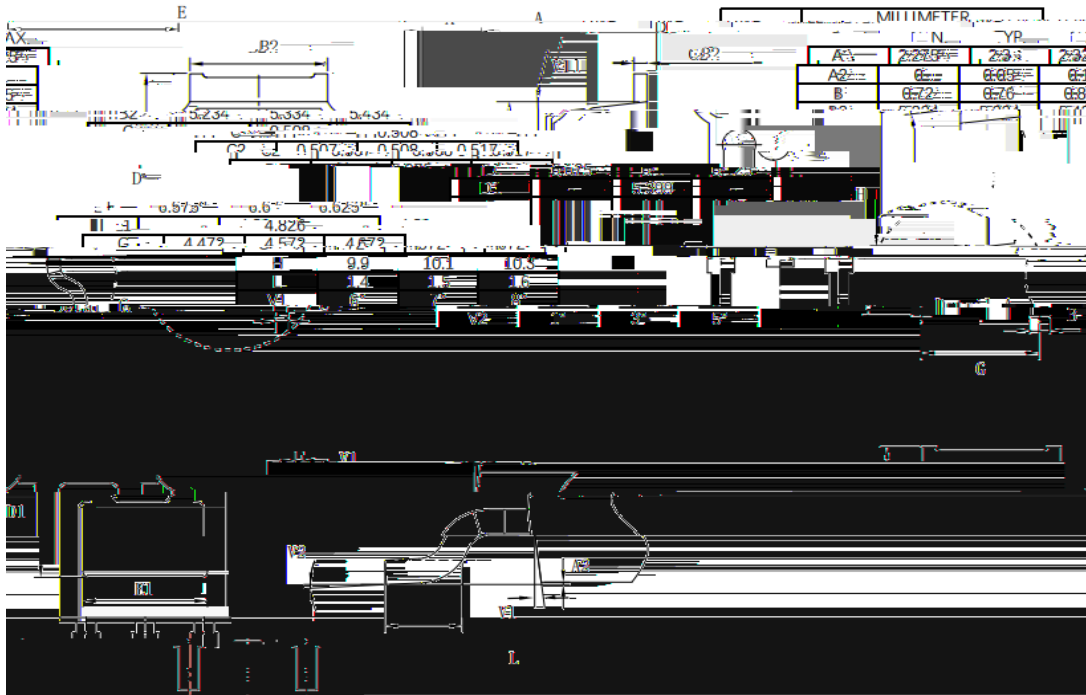
Figure 4: Diode Recovery Test Circuit & Waveform





Package Mechanical Data(TO-252-3L)

Package Outline



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